

# DMA20401

## Silicon PNP epitaxial planar type

For general amplification

### ■ Features

- High forward current transfer ratio  $h_{FE}$  with excellent linearity
- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Halogen-free / RoHS compliant  
(EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

### ■ Marking Symbol: A7

### ■ Basic Part Number

Dual DSA2001 (Individual)

### ■ Packaging

DMA204010R Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

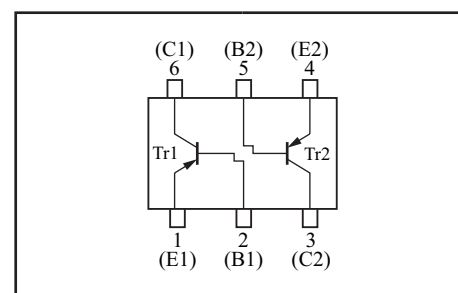
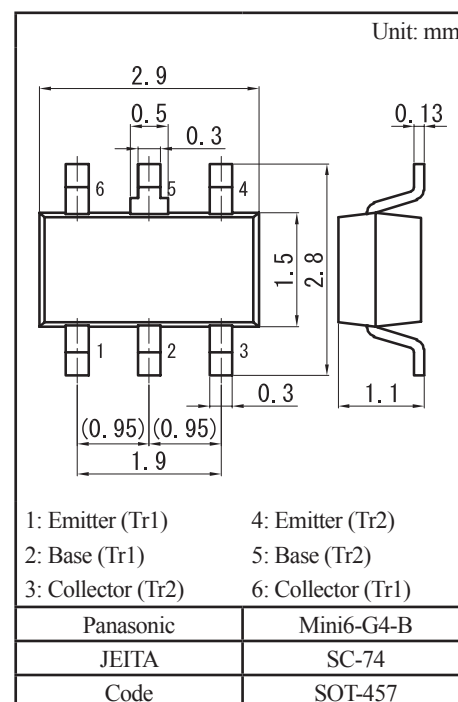
### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

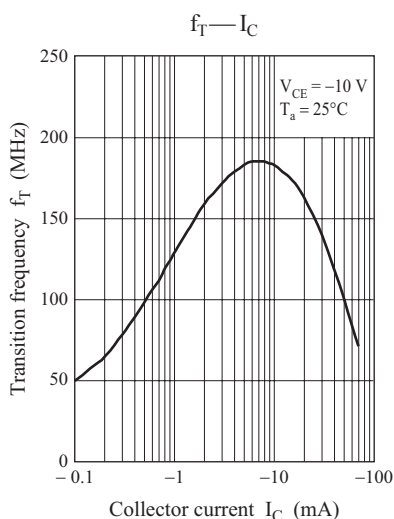
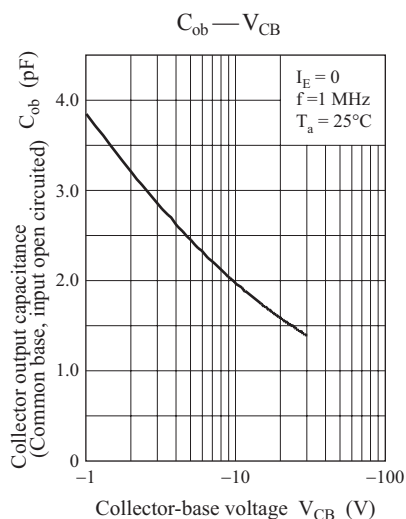
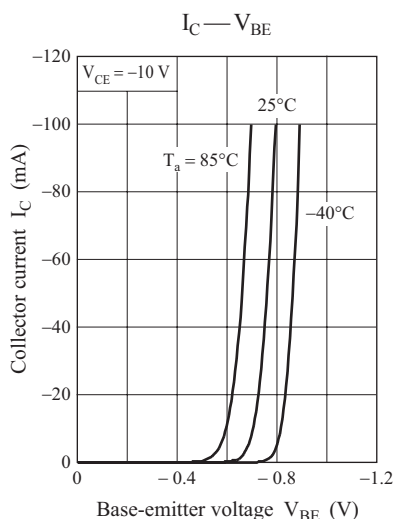
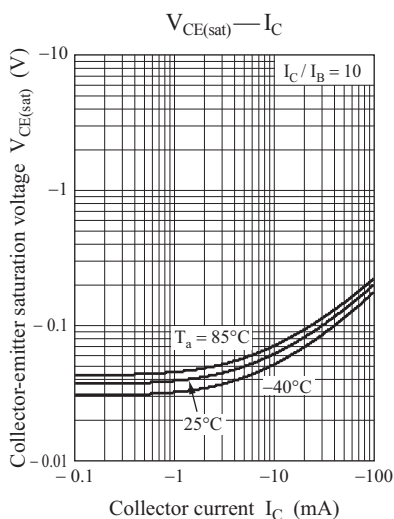
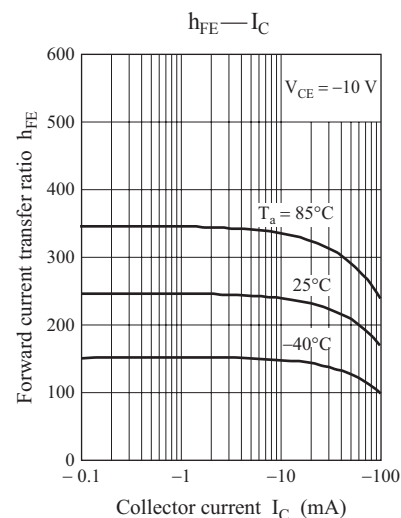
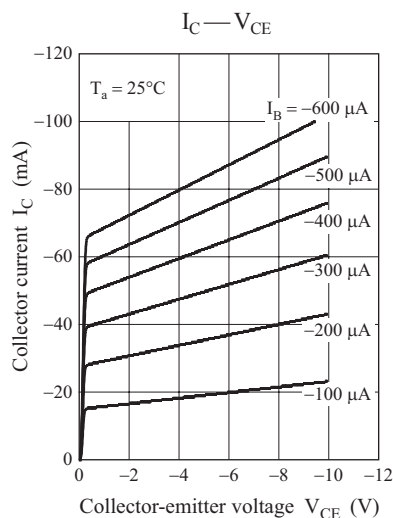
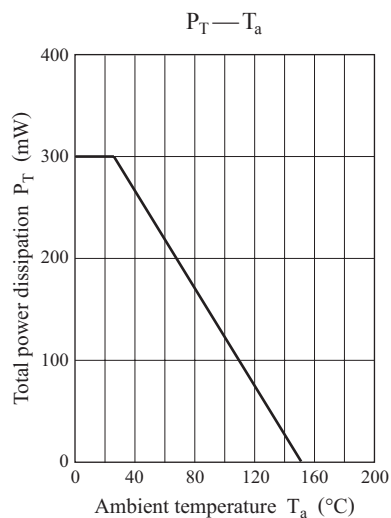
| Parameter  |                                       | Symbol    | Rating      | Unit             |
|------------|---------------------------------------|-----------|-------------|------------------|
| Tr1<br>Tr2 | Collector-base voltage (Emitter open) | $V_{CBO}$ | -60         | V                |
|            | Collector-emitter voltage (Base open) | $V_{CEO}$ | -50         | V                |
|            | Emitter-base voltage (Collector open) | $V_{EBO}$ | -7          | V                |
|            | Collector current                     | $I_C$     | -100        | mA               |
|            | Peak collector current                | $I_{CP}$  | -200        | mA               |
| Overall    | Total power dissipation               | $P_T$     | 300         | mW               |
|            | Junction temperature                  | $T_j$     | 150         | $^\circ\text{C}$ |
|            | Operating ambient temperature         | $T_{opr}$ | -40 to +85  | $^\circ\text{C}$ |
|            | Storage temperature                   | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$ |

### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

| Parameter                                                           | Symbol        | Conditions                                                 | Min | Typ  | Max  | Unit          |
|---------------------------------------------------------------------|---------------|------------------------------------------------------------|-----|------|------|---------------|
| Collector-base voltage (Emitter open)                               | $V_{CBO}$     | $I_C = -10 \mu\text{A}$ , $I_E = 0$                        | -60 |      |      | V             |
| Collector-emitter voltage (Base open)                               | $V_{CEO}$     | $I_C = -2 \text{ mA}$ , $I_B = 0$                          | -50 |      |      | V             |
| Emitter-base voltage (Collector open)                               | $V_{EBO}$     | $I_E = -10 \mu\text{A}$ , $I_C = 0$                        | -7  |      |      | V             |
| Collector-base cutoff current (Emitter open)                        | $I_{CBO}$     | $V_{CB} = -20 \text{ V}$ , $I_E = 0$                       |     |      | -0.1 | $\mu\text{A}$ |
| Collector-emitter cutoff current (Base open)                        | $I_{CEO}$     | $V_{CE} = -10 \text{ V}$ , $I_B = 0$                       |     |      | -100 | $\mu\text{A}$ |
| Forward current transfer ratio                                      | $h_{FE}$      | $V_{CE} = -10 \text{ V}$ , $I_C = -2 \text{ mA}$           | 210 |      | 460  | —             |
| Collector-emitter saturation voltage                                | $V_{CE(sat)}$ | $I_C = -100 \text{ mA}$ , $I_B = -10 \text{ mA}$           |     | -0.2 | -0.5 | V             |
| Transition frequency                                                | $f_T$         | $V_{CE} = -10 \text{ V}$ , $I_C = -2 \text{ mA}$           |     | 150  |      | MHz           |
| Collector output capacitance<br>(Common base, input open circuited) | $C_{ob}$      | $V_{CB} = -10 \text{ V}$ , $I_E = 0$ , $f = 1 \text{ MHz}$ |     | 2    |      | pF            |

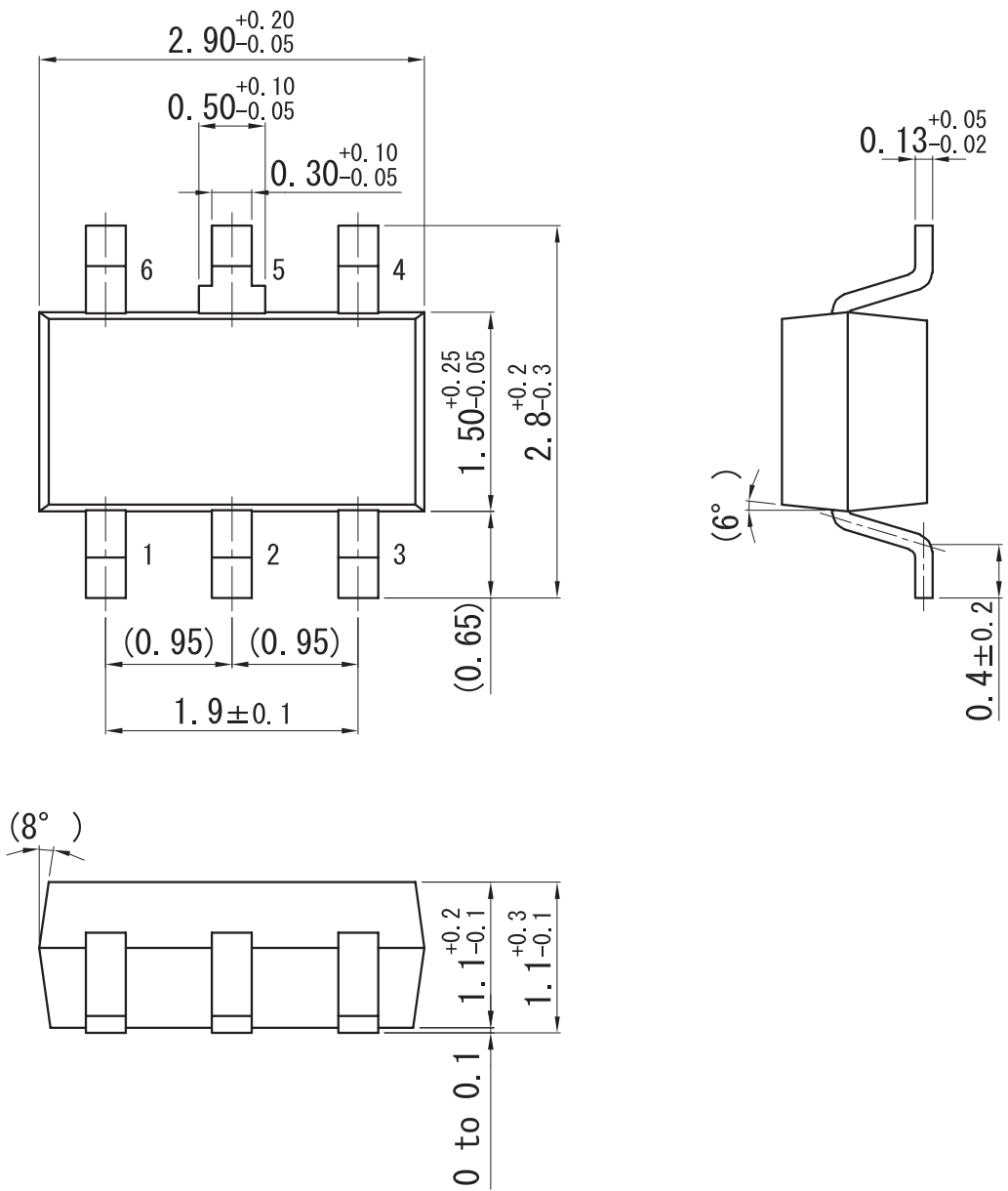
Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.



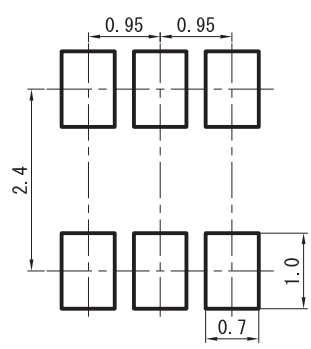


Mini6-G4-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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